



### **60V P-Channel Enhancement Mode MOSFET**

Voltage

-60 V

Current

-14 A

#### **Features**

- $R_{DS(ON)}$ ,  $V_{GS}@-10V$ ,  $I_D@-6A<110m\Omega$
- $R_{DS(ON)}$ ,  $V_{GS}@-4.5V$ ,  $I_D@-3A<130m\Omega$
- High switching speed
- Improved dv/dt capability
- Low Gate Charge
- Low reverse transfer capacitance
- Lead free in compliance with EU RoHS 2011/65/EU directive.
- Green molding compound as per IEC61249 Std. (Halogen Free)

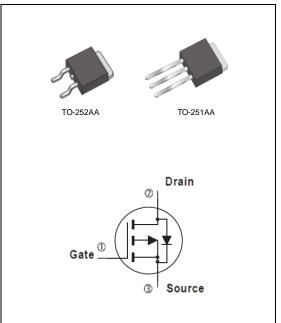


• Case: TO-251AA, TO-252AA Package

• Terminals : Solderable per MIL-STD-750, Method 2026

• TO-251AA Approx. Weight: 0.0104 ounces, 0.297grams

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### Maximum Ratings and Thermal Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		$V_{DS}$	-60	V	
Gate-Source Voltage		$V_{GS}$	<u>+</u> 20	V	
Continuous Drain Current	T <sub>C</sub> =25°C	I <sub>D</sub>	-14	A	
	T <sub>C</sub> =100°C		-9		
Pulsed Drain Current (Note 1)	T <sub>C</sub> =25°C	I <sub>DM</sub>	-42		
Power Dissipation	T <sub>C</sub> =25°C	Po	40	W	
	T <sub>C</sub> =100°C		16		
Continuous Drain Current	T <sub>A</sub> =25°C	I <sub>D</sub>	-3.2	Α	
	T <sub>A</sub> =70°C		-2.5	Α	
Power Dissipation	T <sub>A</sub> =25°C		2.0	W	
Power Dissipation	T <sub>A</sub> =70°C	Pb	1.3		
Single Pulse Avalanche Energy (Note 6)		E <sub>AS</sub>	20	mJ	
Operating Junction and Storage Temperature Range		$T_{J}$ , $T_{STG}$	-55~150	°C	
Typical Thermal Resistance (Note 4,5)	Junction to Case	$R_{ heta JC}$	3.1	°C/W	
	Junction to Ambient	$R_{\theta JA}$	62.5		

Limited only By Maximum Junction Temperature





### **Electrical Characteristics** (T<sub>A</sub>=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static			•			
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V,I <sub>D</sub> =-250uA	-60	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ , $I_{D}=-250uA$	-1.0	-1.7	-2.5	V
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =-10V,I <sub>D</sub> =-6A	-	87	110	mΩ
		$V_{GS}$ =-4.5 $V$ , $I_{D}$ =-3 $A$	-	110	130	
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS}$ =-60V, $V_{GS}$ =0V	-	-	-1.0	uA
Gate-Source Leakage Current	$I_{GSS}$	V <sub>GS</sub> = <u>+</u> 20V,V <sub>DS</sub> =0V	-	-	<u>+</u> 100	nA
Dynamic (Note 7)						
Total Gate Charge	$Q_g$	V <sub>DS</sub> =-30V, I <sub>D</sub> =-4A, V <sub>GS</sub> =-10V <sup>(Note 2,3)</sup>	-	10	-	nC
Gate-Source Charge	$Q_gs$		-	1.6	-	
Gate-Drain Charge	$Q_gd$		-	3	-	
Input Capacitance	Ciss	V 20V V 0V	-	785	-	pF
Output Capacitance	Coss	$V_{DS}$ =-30V, $V_{GS}$ =0V, $f$ =1.0MHZ	-	175	-	
Reverse Transfer Capacitance	Crss	I=1.UIVIHZ	-	112	-	
Turn-On Delay Time	td <sub>(on)</sub>	V 20V PI 200	-	8	-	ns
Turn-On Rise Time	t <sub>r</sub>	$V_{DS}$ =-30V,RL=30 $\Omega$ ,	-	15	-	
Turn-Off Delay Time	td <sub>(off)</sub>	$V_{GS}$ =-10V, $R_{G}$ =6.2 $\Omega$	-	43	-	
Turn-Off Fall Time	t <sub>f</sub>		-	8.4	-	
Drain-Source Diode						
Maximum Continuous Drain-Source			-	-	-14	А
Diode Forward Current	I <sub>S</sub>					
Reverse Recovery Time	$V_{SD}$	I <sub>S</sub> =-1A,V <sub>GS</sub> =0V	-	-0.76	-1.0	V

#### NOTES:

- 1. Pulse width<a></a>300us, Duty cycle<a></a>2%
- 2. Essentially independent of operating temperature typical characteristics
- 3. Repetitive rating, pulse width limited by junction temperature TJ(MAX)=150°C. Ratings are based on low frequency and duty cycles to keep initial TJ =25°C.
- 4. The maximum current rating is package limited
- 5. R<sub>OJA</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch<sup>2</sup> with 2oz.square pad of copper
- 6. L=0.1mH,  $I_{AS}$ =-20A,  $V_{GS}$ =-10V,  $V_{DS}$ =-25V,  $R_{G}$ =25 ohm
- 7. Guaranteed by design, not subject to production testing.





#### **TYPICAL CHARACTERISTIC CURVES**

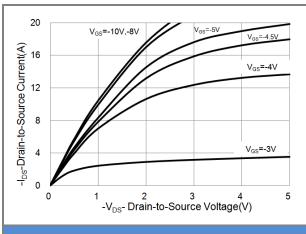
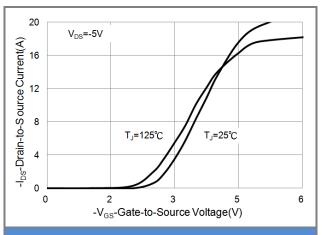


Fig.1 On-Region Characteristics



**Fig.2 Transfer Characteristics** 

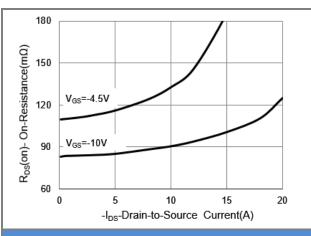


Fig.3 On-Resistance vs. Drain Current

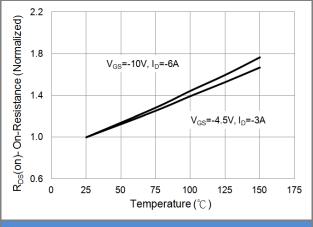


Fig.4 On-Resistance vs. Junction temperature

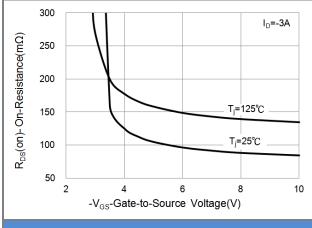


Fig.5 On-Resistance Variation with VGS.

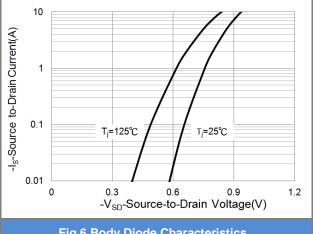


Fig.6 Body Diode Characteristics





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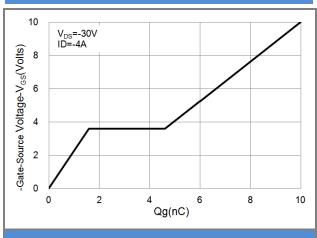


Fig.7 Gate-Charge Characteristics

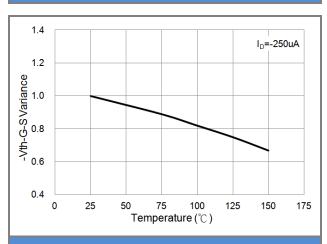
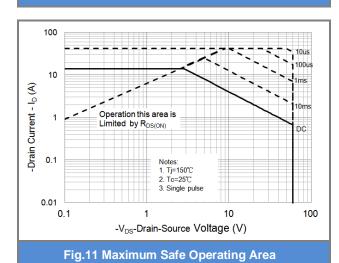


Fig.9 Threshold Voltage Variation with Temperature



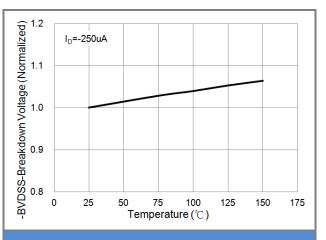


Fig.8 Breakdown Voltage Variation vs. Temperature

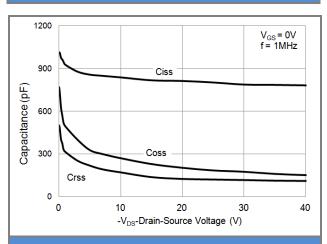


Fig.10 Capacitance vs. Drain-Source Voltage





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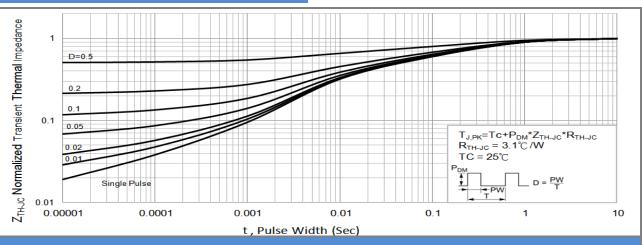
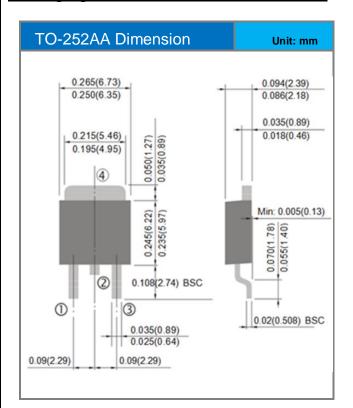


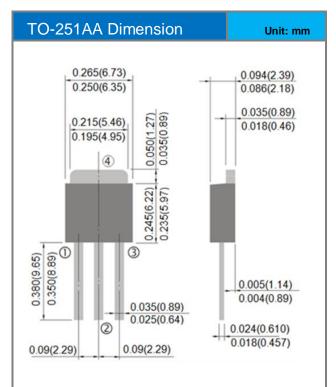
Fig.12 Normalized Thermal Transient Impedance





### **Packaging Information**





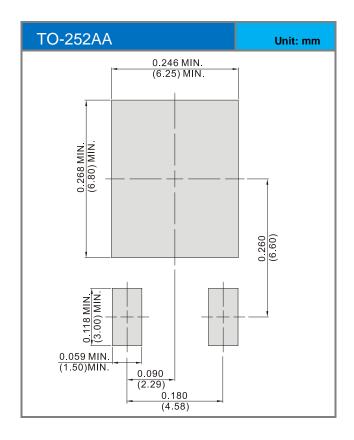




### PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing Type	Marking	Version	
PJU14P06A_T0_00001	TO-251AA	80pcs / Tube	U14P06A	Halogen free	
PJD14P06A_L2_00001	TO-252AA	3,000pcs / 13" reel	D14P06A	Halogen free	

### **MOUNTING PAD LAYOUT**







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